



High-end Power Semiconductor Manufacturer

ZP1000A 1000-1800V Standard Rectifier Diode

- High power cycling capability
- Low on-state and switching losses
- Optimized for line frequency rectifiers
- Designed for traction and industrial applications



Average forward current			I_{FAV}	1000 A				
Repetitive peak reverse voltage			V_{RRM}	1000 – 1800 V				
V_{RRM} , V	1000	1100	1200	1300	1400	1500	1600	1800
Voltage code	10	11	12	13	14	15	16	18
T_j , °C	-60 – 190							

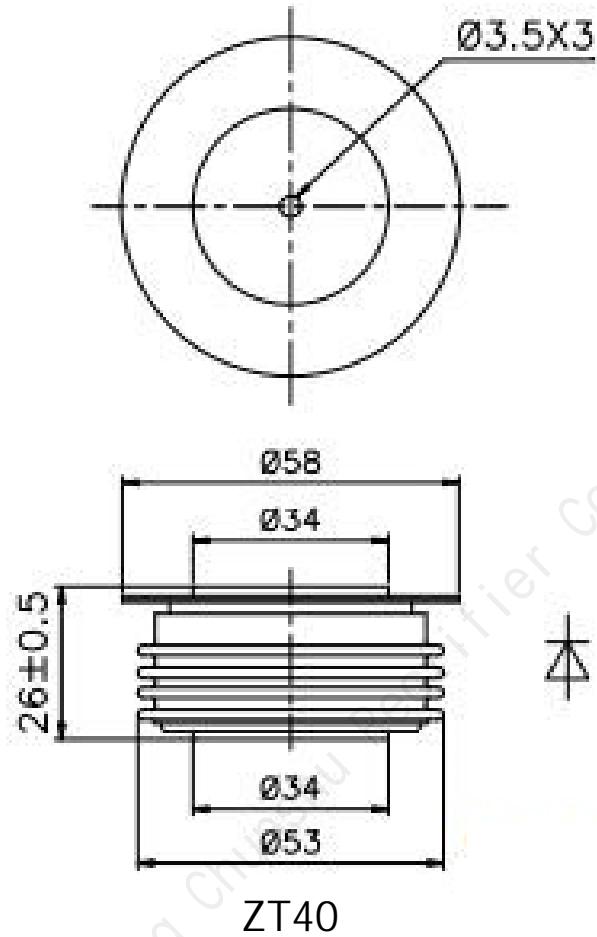
MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values		Test conditions		
ON-STATE							
I_{FAV}	Average forward current		A	1000	$T_c=100$ °C; Double side cooled; 180° half-sine wave; 50 Hz		
I_{FRMS}	RMS forward current		A	1570	$T_c=148$ °C; Double side cooled; 180° half-sine wave; 50 Hz		
I_{FSM}	Surge forward current	kA	18.0	$T_j=T_{j \max}$	180° half-sine wave; 50 Hz	($t_p=10$ ms); single pulse; $V_R=0$ V;	
			21.0	$T_j=25$ °C	19.0	180° half-sine wave; 60 Hz	($t_p=8.3$ ms); single pulse; $V_R=0$ V;
I^2t	Safety factor	$A^2s \cdot 10^3$	1620	$T_j=T_{j \max}$	1620	180° half-sine wave; 50 Hz	($t_p=10$ ms); single pulse; $V_R=0$ V;
			2140	$T_j=25$ °C	1495	180° half-sine wave; 60 Hz	($t_p=8.3$ ms); single pulse; $V_R=0$ V;
BLOCKING							
V_{RRM}	Repetitive peak reverse voltages		V	1000 – 1800	$T_{j \min} < T_j < T_{j \max}$; 180° half-sine wave; 50 Hz;		
V_{RSM}	Non-repetitive peak reverse voltages		V	1100 – 1900	$T_{j \ min} < T_j < T_{j \ max}$; 180° half-sine wave; 50 Hz;single pulse;		
V_R	Reverse continuous voltages		V	$0.75 \cdot V_{RRM}$	$T_j=T_{j \ max}$;		
THERMAL							
T_{stg}	Storage temperature		°C	-60 – 50			
T_j	Operating junction temperature		°C	-60 – 190			
MECHANICAL							
F	Mounting force		kN	14.0 – 16.0			
a	Acceleration		m/s^2	50 100	Device unclamped Device clamped		

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions	
ON-STATE					
V _{FM}	Peak forward voltage, max	V	1.56	T _j =25 °C; I _{FM} =3140 A	
V _{F(TO)}	Forward threshold voltage, max	V	1.02	T _j =T _{j max} ; 0.5 π I _{FAV} < I _T < 1.5 π I _{FAV}	
r _T	Forward slope resistance, max	mΩ	0.237		
BLOCKING					
I _{RRM}	Repetitive peak reverse current, max	mA	70	T _j =T _{j max} ; V _R =V _{RRM}	
THERMAL					
R _{thjc}	Thermal resistance, junction to case, max	°C/W	0.027	Direct current	Double side cooled
R _{thjc-A}			0.059		Anode side cooled
R _{thjc-K}			0.049		Cathode side cooled
R _{thck}	Thermal resistance, case to heatsink, max	°C/W	0.006	Direct current	
MECHANICAL					
w	Weight, typ	g	260		
D _s	Surface creepage distance	mm (inch)	23.69 (0.933)		
D _a	Air strike distance	mm (inch)	19.10 (0.752)		

OVERALL DIMENSIONS



All dimensions in millimeters